

DESCRIPTION

The A2230 is a Class-AB audio power amplifier. It is capable of delivering 1.7 watts of continuous average power to an 4Ω BTL load with less than 10% distortion (THD+N) from a 5V_{DC} power supply, or 1.1 watts continuous average power to an 8Ω BTL load with less than 1% distortion.

The A2230 is designed specifically to provide high quality output power with a minimal amount of external components. It does not require output coupling capacitors or bootstrap capacitors. The A2230 is ideally suited for audio speakers and other low voltage applications.

With special pop-click eliminating circuit, the A2230 provides perfect pop-click characteristic during turn-on and turn-off transitions.

The A2230 is unity-gain stable and can be configured by external gain-setting resistors.

The A2230 is available in SOP8 package.

ORDERING INFORMATION

Package Type	Part Number			
0000		A2230M8R		
SOP8	M8	A2230M8VR		
SPQ: 2,500pcs/Reel, 100pcs/Tube	IVIO	A2230M8U		
10000071000		A2230M8VU		
	V: Halogen free Package			
Note	R: Tape & Reel			
	U: Tube			
AiT provides all RoHS products				

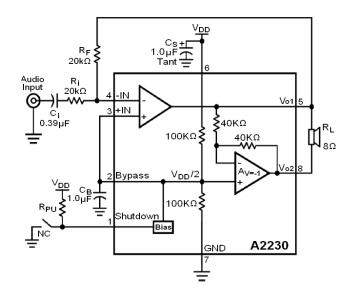
FEATURES

- Improved PSRR at 217 Hz & 1 kHz 60dB
- Power output at 5.0V, 10% THD+N, 4Ω
 1.7 W (typ.)
- Power output at 5.0V, 1% THD+N, 8Ω
 1.1 W (typ.)
- 2.2V ~ 5.5V operation voltage.
- Improved circuitry eliminates pop-click noise during turn-on and turn-off transitions
- No output coupling capacitors, snubber networks or bootstrap capacitors required
- Unity-gain stable
- External gain configuration capability
- Available in SOP8 package.

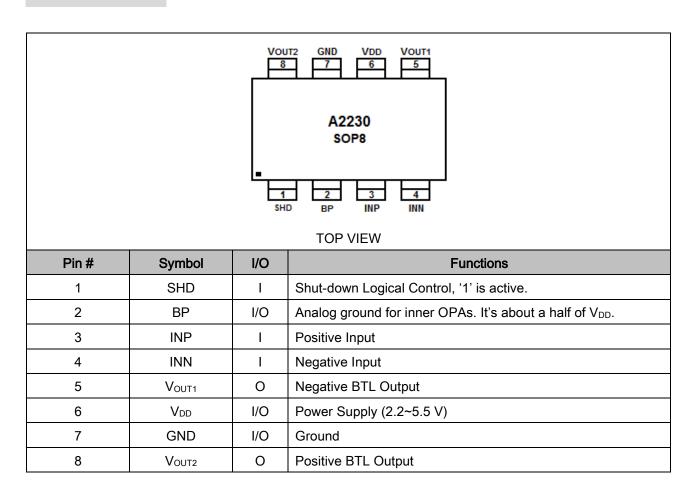
APPLICATION

- Audio speakers
- Desktop computers
- Low voltage audio systems

TYPICAL APPLICATION



PIN DESCRIPTION



EXTERNAL COMPONENTS DESCRIPTION

Components	Functional Description
D:	Inverting input resistance which sets the closed-loop gain in conjunction with Rf. This
Ri	resistor also forms a high pass filter with Ci at fc = $1/(2\pi Ri^*Ci)$.
0:	Input coupling capacitor which blocks the DC voltage at the amplifiers input
Ci	terminates. Also creates a high-pass filter with Ri at fc = $1/(2\pi Ri^*Ci)$.
Dt	Feedback resistance which sets the closed-loop gain in conjunction with Ri. The gain
Rf	is A _{VD} =2*(Rf/Ri).
Cs	Supply bypass capacitor which provides power supply filtering.
Cb	Bypass pin capacitor which provides half-supply filtering. Refer to the section.



ABSOLUTE MAXIMUM RATINGS

Supply Voltage	-0.3V~6.0V
Input Voltage	-0.3V~V _{DD} +0.3V
Power dissipation	See Dissipation Rating Table
Junction Temperature	-40°C~+150°C
Storage Temperature	-65°C~+150°C
Thermal Resistance	
θ _{JA} (SOP8)	184°C/W

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

OPERATING RATINGS

Parameter	Value
Temperature Range	-40°C ≤ T _A ≤ 85°C
Supply Voltage	2.2V ≤ V _{DD} ≤ 5.5V



ELECTRICAL CHARACTERISTICS

The following specifications apply for the circuit shown in Figure 1, unless otherwise specified. Limits apply for $T_A = 25$ °C.

 $V_{DD} = 5V$

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Quiescent Power Supply	,	V _{IN} = 0V, 8Ω Load	-	3.0	8.0	т Л	
Current	I_{DD}	V _{IN} = 0V, No Load	-	2.5	7.0	mA	
Shutdown Current	I _{SD}	V _{IN} =0V, V _{SHD} =GND, No Load	-	0.5	-	μΑ	
Shutdown Voltage Input High	Vsdih		1.2	-	-	V	
Shutdown Voltage Input Low	V _{SDIL}		-	-	0.9	٧	
Output Offset Voltage	Vos		-50	6.0	50	mV	
Total Harmonic Distortion + Noise	THD+N	Po=0.5Wrms, f=1KHz	-	0.07	-	%	
Outsid Barrer	Б	THD+N<=1%, f=1kHz, 8Ω Load	-	1.1	-	W	
Output Power	Po	THD+N<=10%, f=1kHz, 4Ω Load	-	1.7	-		
Decree Or and Decree Decree	DODD	Input terminated with 10Ω, VDDRIPPLE=0.2VP-P, f=217Hz	-	60	-	dB	
Power Supply Rejection Ratio	PSRR	Input terminated with 10Ω, VDDRIPPLE=0.2VP-P, f=1kHz	-	61	-	dB	
Wake-up Time	Twu		-	100	-	ms	

 $V_{DD} = 3V$

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Quiescent Power Supply	1	V _{IN} = 0V, 8Ω Load	-	2	7	m 1	
Current	I _{DD}	V _{IN} = 0V, No Load	-	1.5	6	mA	
Shutdown Current	Isd	V _{IN} =0V, V _{SHD} =GND, No Load	-	0.5	-	μΑ	
Shutdown Voltage Input High	V _{SDIH}		1.0	-	-	V	
Shutdown Voltage Input Low	V _{SDIL}		-	-	0.7	V	
Output Offset Voltage	Vos		-50	6	50	mV	
Total Harmonic Distortion + Noise	THD+N	Po=0.25Wrms, f=1kHz	-	0.08	-	%	
Output Power	Po	THD+N<=1%, f=1kHz, 8Ω Load	-	310	-	mW	
David Complete Daire than Datio	DCDD	Input terminated with 10Ω, VDDRIPPLE=0.2VP-P, f=217Hz	-	57	-	dB	
Power Supply Rejection Ratio	PSRR	Input terminated with 10Ω, VDDRIPPLE=0.2VP-P, f=1kHz	-	58	-	dB	
Wake-up Time	Twυ		-	75	-	ms	

TYPICAL APPLICATION CIRCUIT

 $20k\Omega$

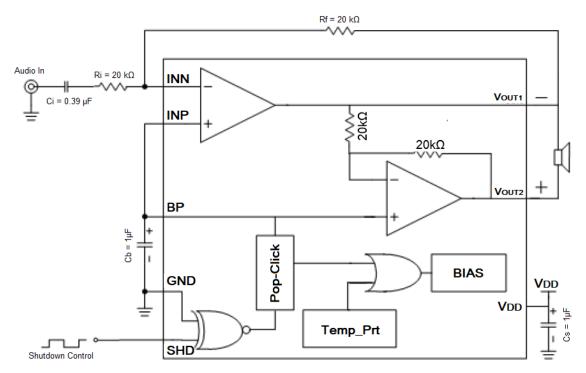


Figure 1. A2230 Typical Application Circuit

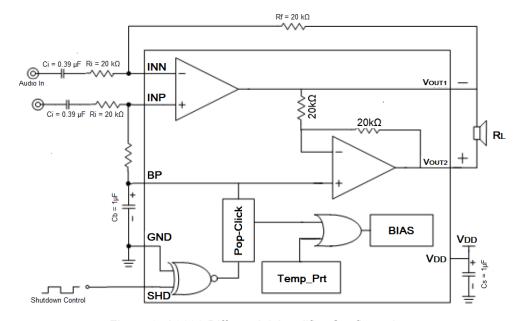
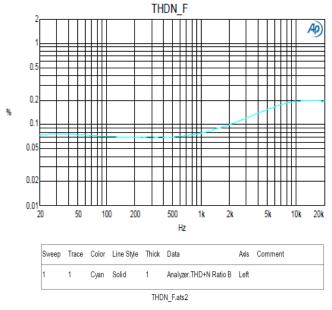


Figure 2. A2230 Differential Amplifier Configuration

TYPICAL PERFORMANCE CHARACTERISTICS

1. THDN vs. Frequency V_{DD} =5V R_L=8 Ω P_O=500mW



3. THDN vs. Output Power

0.02

0.01

 $V_{DD}=5V R_{L}=8\Omega F=1kHz$

200m

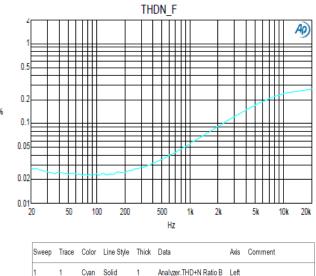


300m



400m 500m 600m

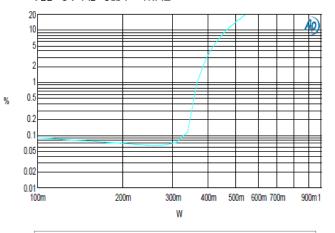
2. THDN vs. Frequency V_{DD} =3V R_L=8 Ω P_O=250mW



Sweep	Trace	Color	Line Style	Thick	Data	Axis	Comment
1	1	Cyan	Solid	1	Analyzer.THD+N Ratio B	Left	
THDN_F.ats2							

THDN vs. Output Power

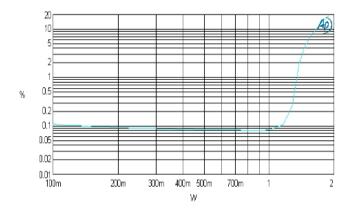
V_{DD} =3V R_L=8 Ω F=1kHz



Sweep	Trace	Color	Line Style	Thick	Data	Axis	Comment
1	1	Cyan	Solid	1	Analyzer.THD+N Ratio B	Left	
THDN_F.ats2							



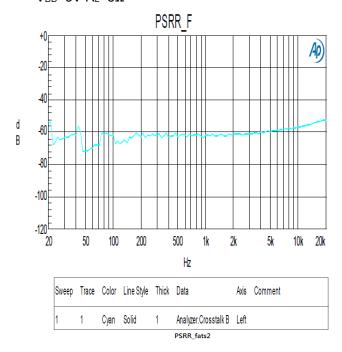
5. THDN vs. Output Power V_{DD}=5V R_L=4Ω F=1kHz



Sweep	Trace	Color	Line Style	Thick	Data	Axis	Comment
1	1	Cyan	Solid	1	Analyzer.THD+N Ratio B	Left	
	THDN_F.ats2						

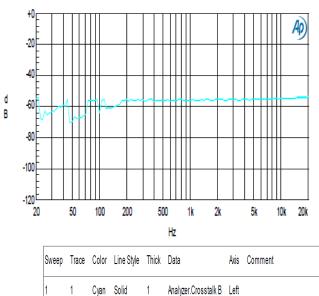
7. PSRR vs. Frequency

 V_{DD} =3V R_L =8 Ω



6. PSRR vs. Frequency

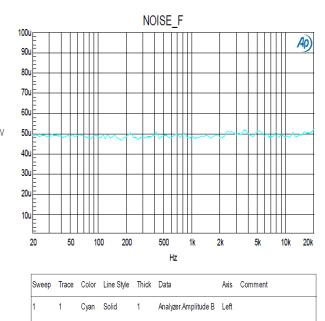
 $V_{DD}=5V R_{L}=8\Omega$



PSRR_fats2

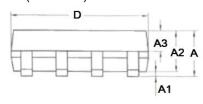
8. Noise Floor 20kBW

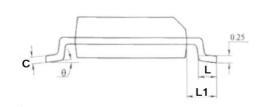
 V_{DD} =5 $V R_L$ =8 Ω

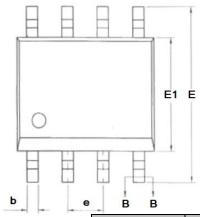


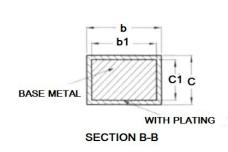
PACKAGE INFORMATION

Dimension in SOP8 (Unit: mm)









Symbol	Min	Max		
А	-	1.77		
A1	0.08	0.28		
A2	1.20	1.60		
A3	0.55	0.75		
b	0.39	0.48		
b1	0.38	0.43		
С	0.21	0.26		
c1	0.19	0.21		
D	4.70	5.10		
Е	5.80	6.20		
E1	3.70	4.10		
е	1.27 BSC			
L	0.50	0.80		
L1	1.05 BSC			
θ	0°	8°		

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